

## High Efficiency LED in $\varnothing$ 3 mm Clear Package

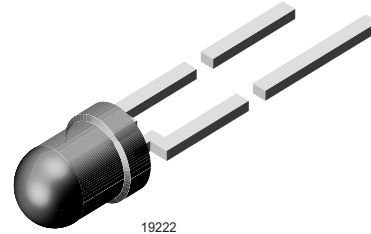
### Description

The TLH.4900 series was developed for applications where high light output is required.

It is housed in a 3 mm clear plastic package. The small viewing angle of these devices provides a high brightness.

All LEDs are categorized in luminous intensity groups. The green and yellow LEDs are categorized additionally in wavelength groups.

That allows users to assemble LEDs with uniform appearance.



19222



### Features

- Choice of five bright colors
- Standard  $\varnothing$  3 mm (T-1) package
- Small mechanical tolerances
- Suitable for DC and high peak current
- Very small viewing angle
- Luminous intensity categorized
- Yellow and green color categorized
- Lead-free device

### Applications

- Status lights
- OFF / ON indicator
- Background illumination
- Readout lights
- Maintenance lights
- Legend light

### Parts Table

Part	Color, Luminous Intensity	Angle of Half Intensity ( $\pm\phi$ )	Technology
TLHR4900	Red, $I_V > 6.3$ mcd	16 °	GaAsP on GaP
TLHO4900	Soft orange, $I_V > 10$ mcd	16 °	GaAsP on GaP
TLHY4900	Yellow, $I_V > 10$ mcd	16 °	GaAsP on GaP
TLHG4900	Green, $I_V > 16$ mcd	16 °	GaP on GaP
TLHP4900	Pure green, $I_V > 4$ mcd	16 °	GaP on GaP

### Absolute Maximum Ratings

$T_{amb} = 25$  °C, unless otherwise specified

**TLHR4900 , TLHO4900 , TLHY4900 , TLHP4900**

Parameter	Test condition	Symbol	Value	Unit
Reverse voltage		$V_R$	6	V
DC Forward current	$T_{amb} \leq 60$ °C	$I_F$	30	mA
Surge forward current	$t_p \leq 10$ $\mu$ s	$I_{FSM}$	1	A
Power dissipation	$T_{amb} \leq 60$ °C	$P_V$	100	mW
Junction temperature		$T_j$	100	°C
Operating temperature range		$T_{amb}$	- 40 to + 100	°C

Parameter	Test condition	Symbol	Value	Unit
Storage temperature range		$T_{stg}$	- 55 to + 100	°C
Soldering temperature	$t \leq 5$ s, 2 mm from body	$T_{sd}$	260	°C
Thermal resistance junction/ambient		$R_{thJA}$	400	K/W

## Optical and Electrical Characteristics

$T_{amb} = 25$  °C, unless otherwise specified

### Red

#### TLHR4900

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Luminous intensity <sup>1)</sup>	$I_F = 10$ mA	$I_V$	6.3	13		mcd
Dominant wavelength	$I_F = 10$ mA	$\lambda_d$	612		625	nm
Peak wavelength	$I_F = 10$ mA	$\lambda_p$		635		nm
Angle of half intensity	$I_F = 10$ mA	$\phi$		$\pm 16$		deg
Forward voltage	$I_F = 20$ mA	$V_F$		2	3	V
Reverse voltage	$I_R = 10$ $\mu$ A	$V_R$	6	15		V
Junction capacitance	$V_R = 0$ , $f = 1$ MHz	$C_j$		50		pF

<sup>1)</sup> in one Packing Unit  $I_{Vmin}/I_{Vmax} \leq 0.5$

### Soft Orange

#### TLHO4900

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Luminous intensity <sup>1)</sup>	$I_F = 10$ mA	$I_V$	10	26		mcd
Dominant wavelength	$I_F = 10$ mA	$\lambda_d$	598		611	nm
Peak wavelength	$I_F = 10$ mA	$\lambda_p$		605		nm
Angle of half intensity	$I_F = 10$ mA	$\phi$		$\pm 16$		deg
Forward voltage	$I_F = 20$ mA	$V_F$		2.4	3	V
Reverse voltage	$I_R = 10$ $\mu$ A	$V_R$	6	15		V
Junction capacitance	$V_R = 0$ , $f = 1$ MHz	$C_j$		50		pF

<sup>1)</sup> in one Packing Unit  $I_{Vmin}/I_{Vmax} \leq 0.5$

### Yellow

#### TLHY4900

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Luminous intensity <sup>1)</sup>	$I_F = 10$ mA	$I_V$	10	26		mcd
Dominant wavelength	$I_F = 10$ mA	$\lambda_d$	581		594	nm
Peak wavelength	$I_F = 10$ mA	$\lambda_p$		585		nm
Angle of half intensity	$I_F = 10$ mA	$\phi$		$\pm 16$		deg
Forward voltage	$I_F = 20$ mA	$V_F$		2.4	3	V
Reverse voltage	$I_R = 10$ $\mu$ A	$V_R$	6	15		V
Junction capacitance	$V_R = 0$ , $f = 1$ MHz	$C_j$		50		pF

<sup>1)</sup> in one Packing Unit  $I_{Vmin}/I_{Vmax} \leq 0.5$

## Green

TLHG4900

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Luminous intensity <sup>1)</sup>	$I_F = 10 \text{ mA}$	$I_V$	16	37		mcd
Dominant wavelength	$I_F = 10 \text{ mA}$	$\lambda_d$	562		575	nm
Peak wavelength	$I_F = 10 \text{ mA}$	$\lambda_p$		565		nm
Angle of half intensity	$I_F = 10 \text{ mA}$	$\phi$		$\pm 16$		deg
Forward voltage	$I_F = 20 \text{ mA}$	$V_F$		2.4	3	V
Reverse voltage	$I_R = 10 \mu\text{A}$	$V_R$	6	15		V
Junction capacitance	$V_R = 0, f = 1 \text{ MHz}$	$C_j$		50		pF

<sup>1)</sup> in one Packing Unit  $I_{Vmin}/I_{Vmax} \leq 0.5$

## Pure green

TLHP4900

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Luminous intensity <sup>1)</sup>	$I_F = 10 \text{ mA}$	$I_V$	4	13		mcd
Dominant wavelength	$I_F = 10 \text{ mA}$	$\lambda_d$	555		565	nm
Peak wavelength	$I_F = 10 \text{ mA}$	$\lambda_p$		555		nm
Angle of half intensity	$I_F = 10 \text{ mA}$	$\phi$		$\pm 16$		deg
Forward voltage	$I_F = 20 \text{ mA}$	$V_F$		2.4	3	V
Reverse voltage	$I_R = 10 \mu\text{A}$	$V_R$	6	15		V
Junction capacitance	$V_R = 0, f = 1 \text{ MHz}$	$C_j$		50		pF

<sup>1)</sup> in one Packing Unit  $I_{Vmin}/I_{Vmax} \leq 0.5$

## Typical Characteristics ( $T_{amb} = 25 \text{ }^\circ\text{C}$ unless otherwise specified)

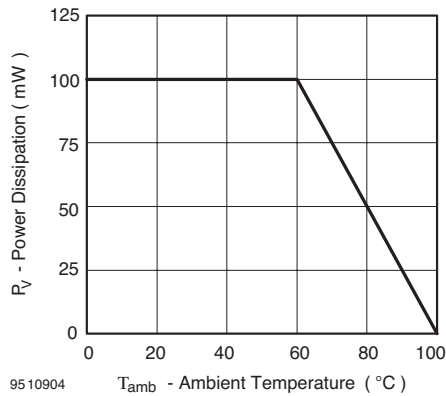


Figure 1. Power Dissipation vs. Ambient Temperature

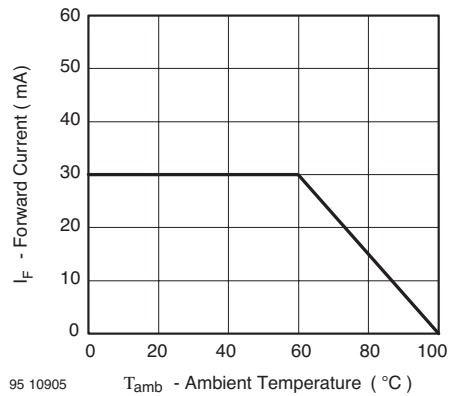


Figure 2. Forward Current vs. Ambient Temperature for InGaN

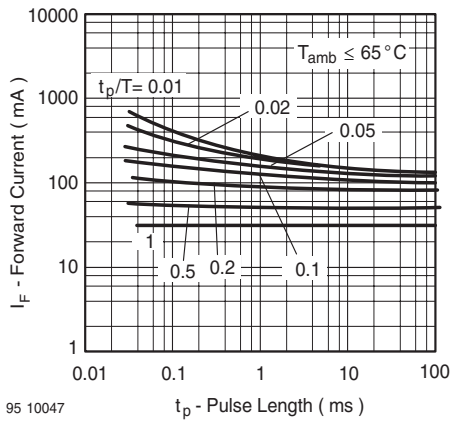


Figure 3. Forward Current vs. Pulse Length

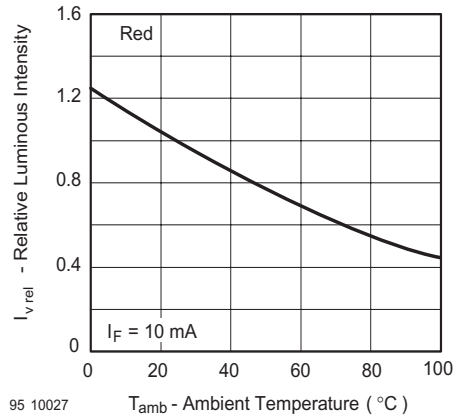


Figure 6. Rel. Luminous Intensity vs. Ambient Temperature

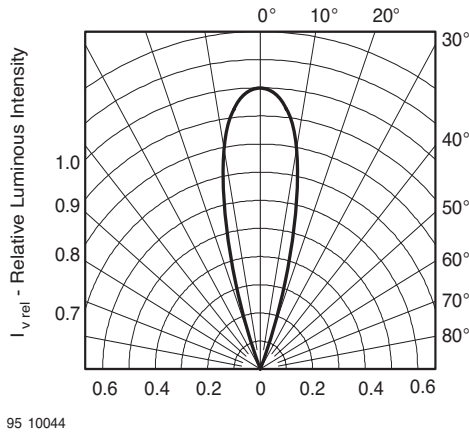


Figure 4. Rel. Luminous Intensity vs. Angular Displacement

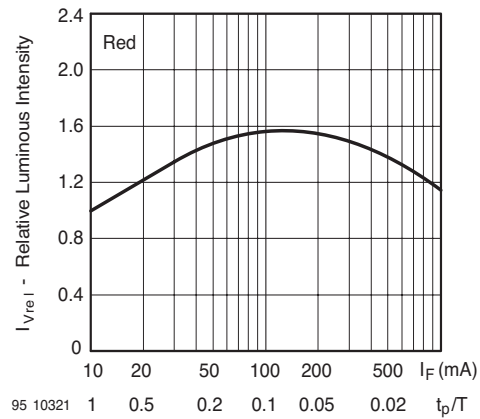


Figure 7. Rel. Luminous Intensity vs. Forw. Current/Duty Cycle

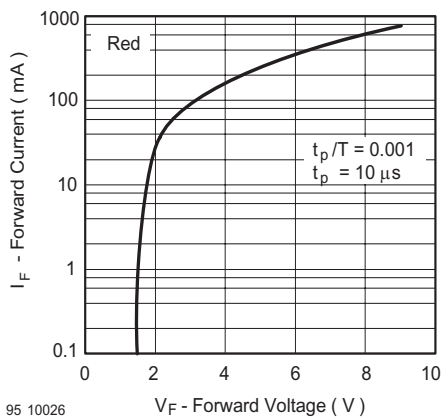


Figure 5. Forward Current vs. Forward Voltage

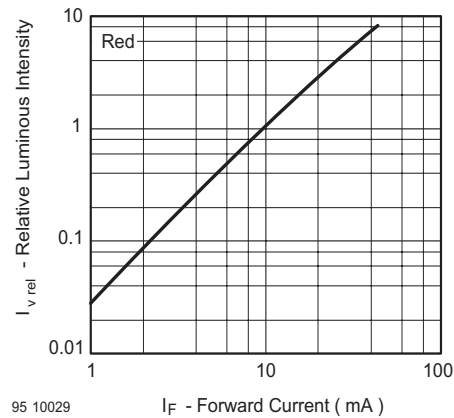


Figure 8. Relative Luminous Intensity vs. Forward Current

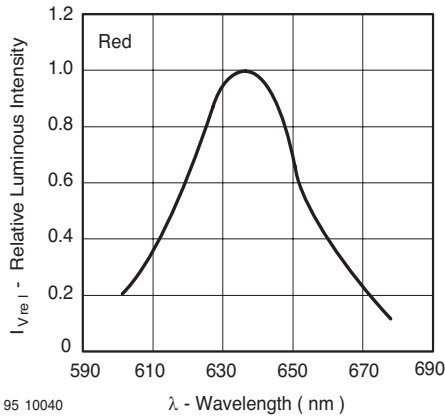


Figure 9. Relative Intensity vs. Wavelength

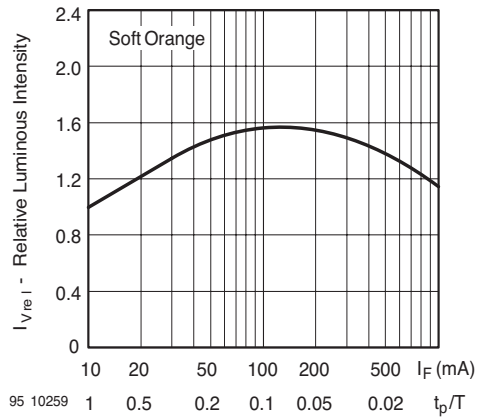


Figure 12. Rel. Lumin. Intensity vs. Forw. Current/Duty Cycle

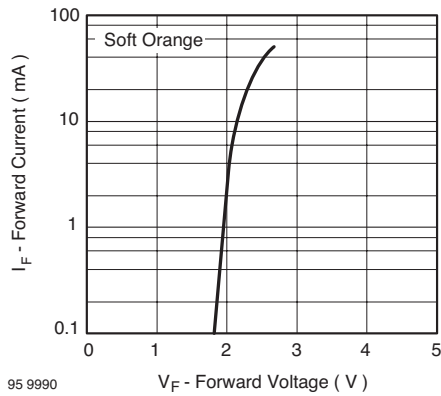


Figure 10. Forward Current vs. Forward Voltage

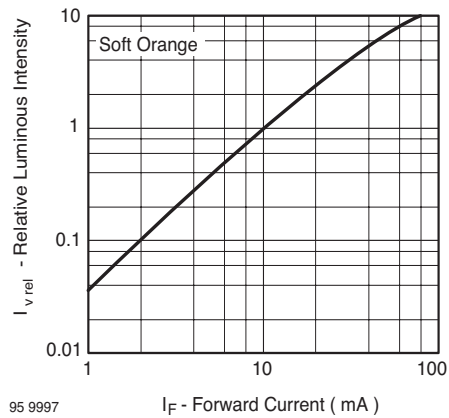


Figure 13. Relative Luminous Intensity vs. Forward Current

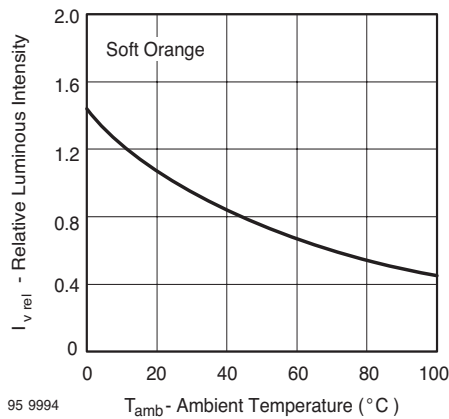


Figure 11. Rel. Luminous Intensity vs. Ambient Temperature

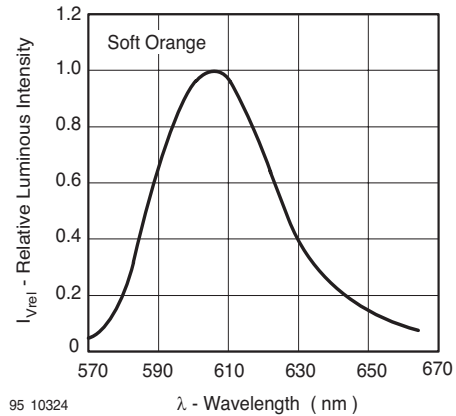


Figure 14. Relative Intensity vs. Wavelength

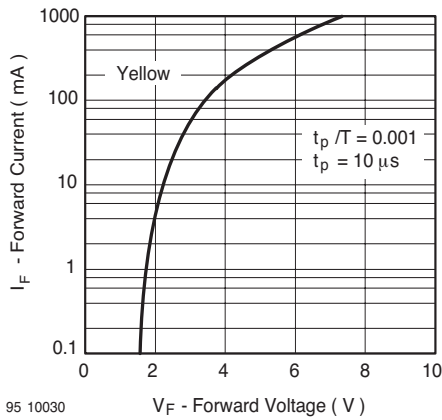


Figure 15. Forward Current vs. Forward Voltage

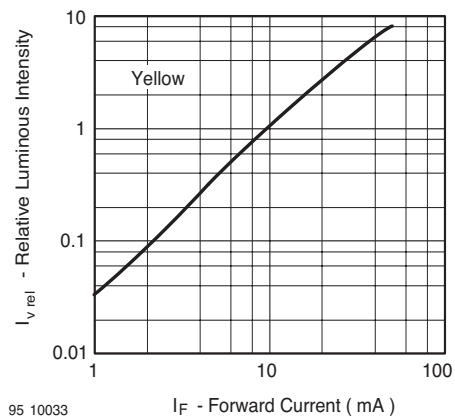


Figure 18. Relative Luminous Intensity vs. Forward Current

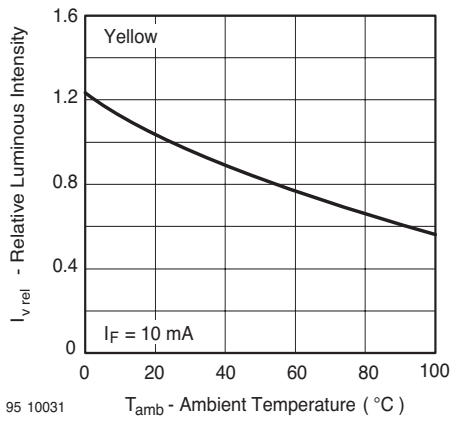


Figure 16. Rel. Luminous Intensity vs. Ambient Temperature

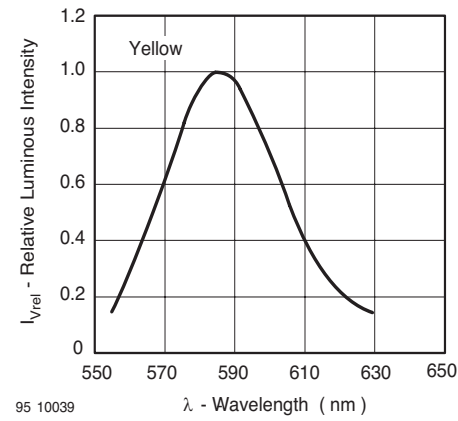


Figure 19. Relative Intensity vs. Wavelength

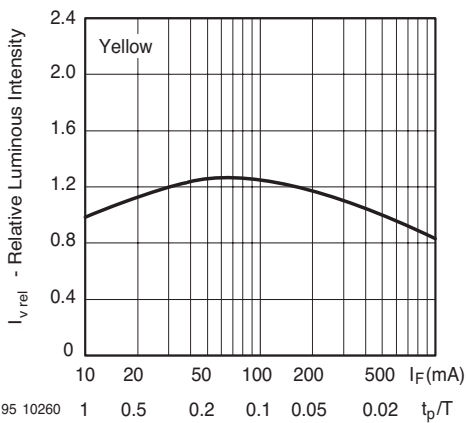


Figure 17. Rel. Lumin. Intensity vs. Forw. Current/Duty Cycle

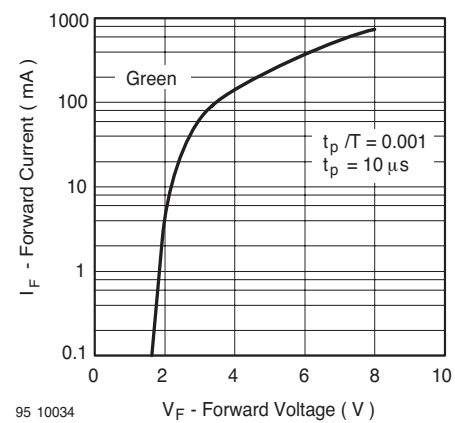


Figure 20. Forward Current vs. Forward Voltage

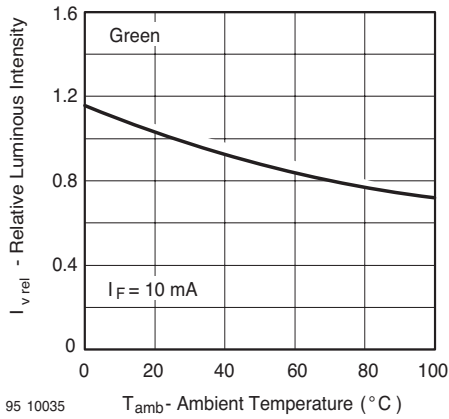


Figure 21. Rel. Luminous Intensity vs. Ambient Temperature

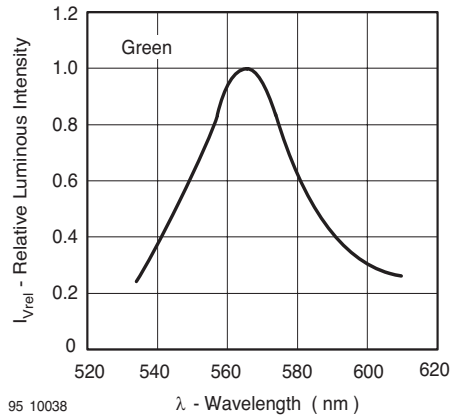


Figure 24. Relative Intensity vs. Wavelength

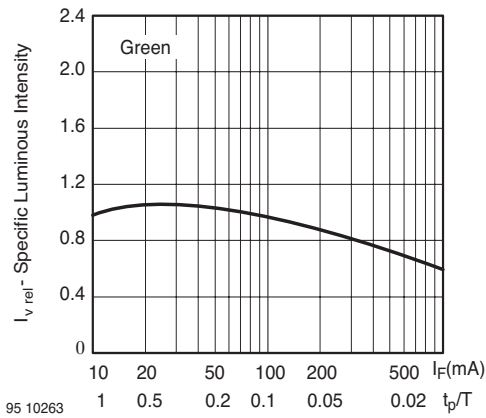


Figure 22. Specific Luminous Intensity vs. Forward Current

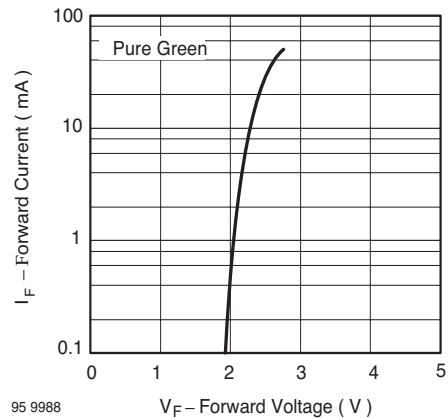


Figure 25. Forward Current vs. Forward Voltage

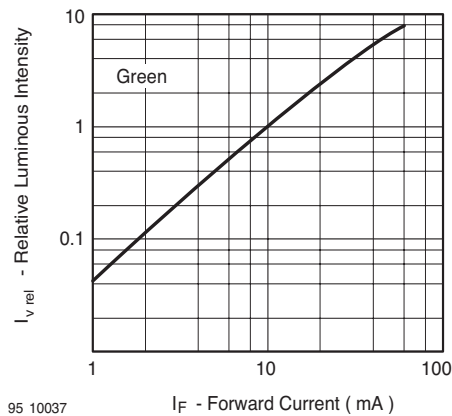


Figure 23. Relative Luminous Intensity vs. Forward Current

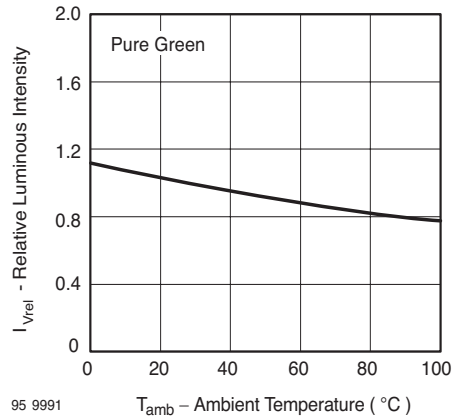


Figure 26. Rel. Luminous Intensity vs. Ambient Temperature

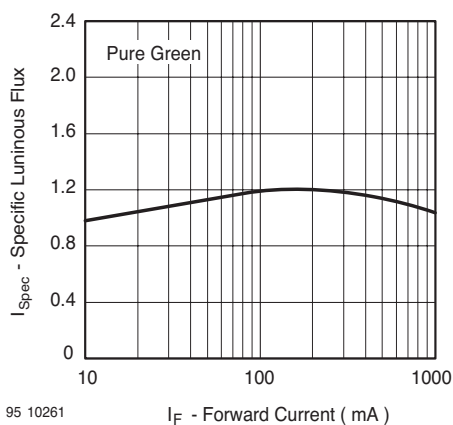


Figure 27. Specific Luminous Intensity vs. Forward Current

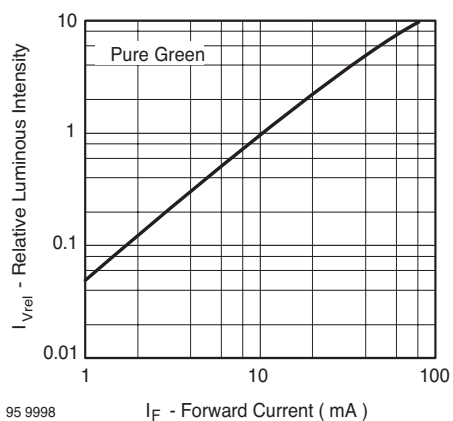


Figure 28. Relative Luminous Intensity vs. Forward Current

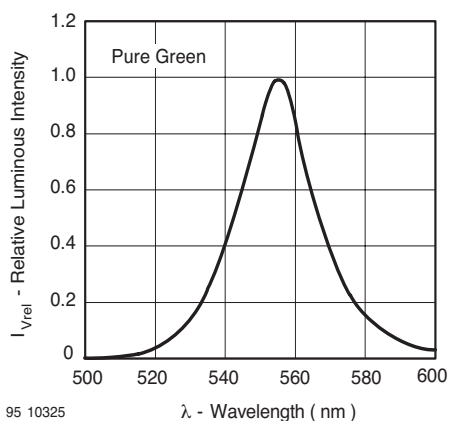
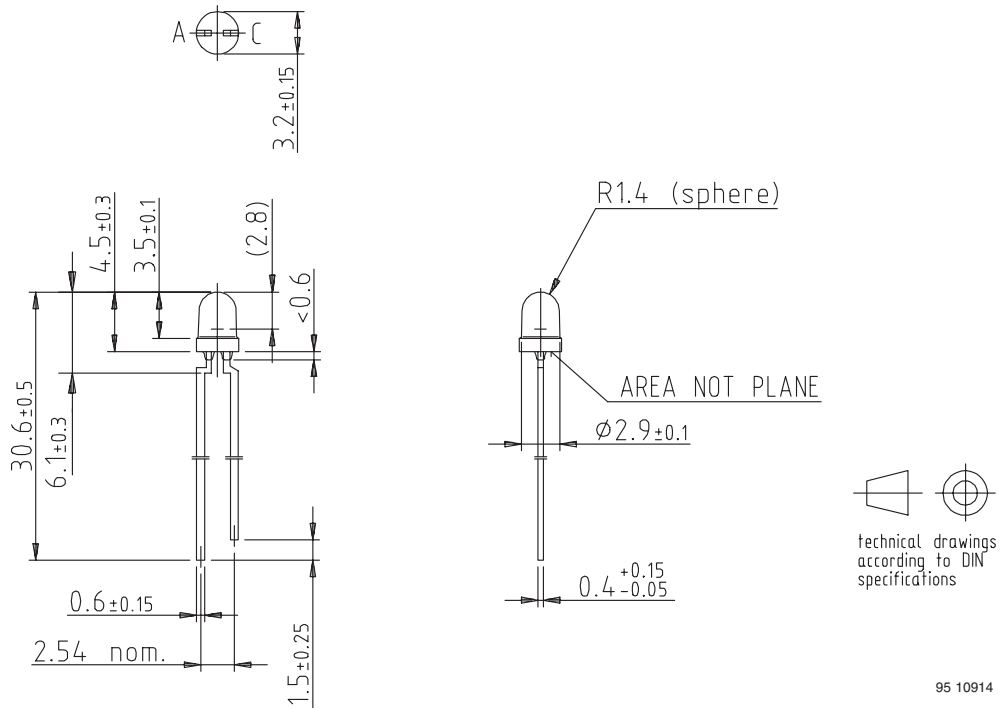


Figure 29. Relative Intensity vs. Wavelength



## Package Dimensions in mm



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2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

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The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

**Vishay Semiconductor GmbH** has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

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2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

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На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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